## **MOSPEC**

### MIG20120D

#### 1200V Silicon Carbide Schottky Diode

#### DESCRIPTION :

- Positive temperature Coefficient
- High Speed Switching
- Negligible reverse recovery
- Temperature Independent Switching
- RoHS Compliant

#### TYPICAL APPLICATIONS :

- Uninterruptible power supplies (UPS)
- Data Center
- Switch mode power supplies
- Solar inverters

V <sub>RRM</sub>	1200V	
I <sub>F</sub>	10/20A (TC=159°C)	
Q <sub>C</sub>	52/104nC	



TO-247AB

#### MAXIMUM RATINGS (at T<sub>C</sub> = 25 °C, unless otherwise specified)

Characteristic	Condition	Symbol	Value	Unit
Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	1200	V
Continuous Forward Current	Tc=25℃ Tc=135℃ Tc=159℃	I <sub>F</sub>	36 / 72 18 / 36 10 / 20	А
Non-Repetitive Forward Surge Current	Tc=25°C , t_P=10ms, Half sine pulse Tc=110°C , t_P=10ms, Half sine pulse	I <sub>FSM</sub>	60 / 120 45 / 90	А
Repetitive Peak Forward Surge Current	Tc=25 $^\circ\!\!\mathbb{C}$ , tp=10ms, Half sine pulse	I <sub>FRM</sub>	55 / 110	А
i <sup>2</sup> t value	Tc=25℃ , tբ=10ms Tc=110℃ , tբ=10ms	∫ i²dt	18 / 72 10 / 41	A <sup>2</sup> S
Power dissipation	Tc=25℃ Tc=110℃ Tc=150℃	P <sub>tot</sub>	204 / 408 88 / 176 34 / 68	W
Operation Junction temperature		Tj	-55~+175	°C
Storage temperature		T <sub>STG</sub>	-55~+175	°C

#### MIG20120D

# THERMAL CHARACTERISTICS Characteristic Condition Symbol Typical Unit Thermal resistance, junction - case R<sub>th(j-C)</sub> 0.736 °C/W

#### ELECTRICAL CHARATERISTICS (at $T_c = 25$ °C, unless otherwise specified)

Characteristic	Symbol	Min.	Тур.	Max.	Unit
DC Blocking Voltage	V <sub>DC</sub>	1200			V
Forward Voltage IF = 5A IF = 10A, Tc =25°C IF = 10A, Tc =175°C	V <sub>F</sub>		1.20 1.43 2.00	1.7	V
Reverse Current VR = 1200V, Tc =25℃ VR = 1200V, Tc =175℃	I <sub>R</sub>		2 4	60	uA
Total Capacitive Charge VR = 800V	Q <sub>C</sub>		52		nC
Total capacitance VR = 1V, f =1MHz VR = 400V, f =1MHz VR = 800V, f =1MHz	С		546 47 41		pF
Capacitance Stored Energy VR = 800 V	Ec		15.86		uJ

#### MIG20120D

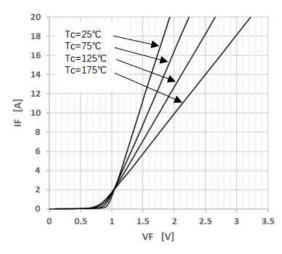


Figure 1. Forward characteristics

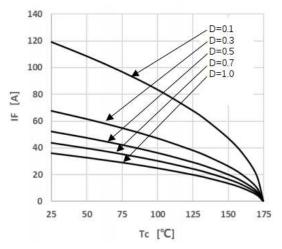


Figure 3. Peak Forward Current Derating

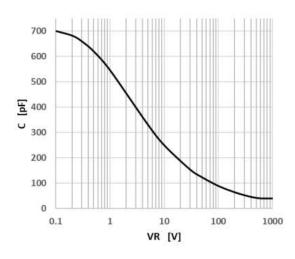


Figure 5. Capacitance vs. Reverse Voltage

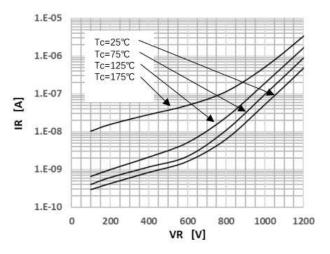


Figure 2. Reverse characteristics

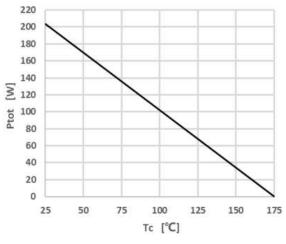


Figure 4. Power Dissipation

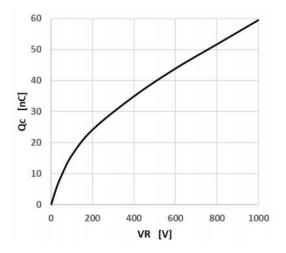


Figure 6. Capacitance Charge vs. Reverse Voltage

#### MIG20120D

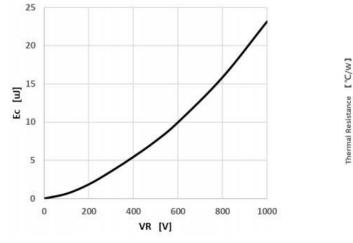


Figure 7. Capacitance Stored Energy

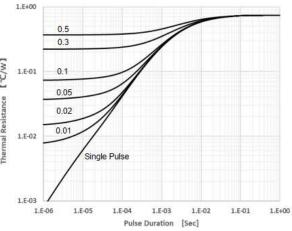
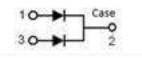
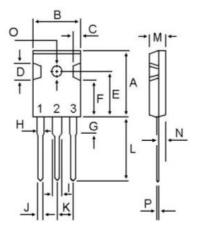


Figure 8. Transient Thermal Impedance

Circuit diagram



TO-247AB Package outlines : Dimensions in (mm)



DIM	MILLIMETERS		
DIN	MIN	MAX	
Α	20.80	21.80	
В	15.38	16.20	
С	1.90	2.70	
D	5.10	6.10	
ш	14.50	15.50	
F	11.20	13.20	
G	3.75	4.35	
Н	1.90	2.30	
-	2.90	3.30	
J	1.00	1.40	
K	5.26	5.66	
L	19.50	20.50	
М	4.68	5.36	
Ν	2.30	2.60	
0	3.45	3.85	
Р	0.48	0.72	



#### Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life ( atomic energy control, aeronautics , traffic control, combustion control, safety devices etc.)